Power logic 8-bit shift register; open-drain outputs Rev. 1 — 18 October 2013 Produ

Product data sheet

1. General description

The NPIC6C596A-Q100 is an 8-bit serial-in/serial or parallel-out shift register with a storage register and open-drain outputs. Both the shift and storage register have separate clocks. The device features a serial input (DS) and a serial output (Q7S) to enable cascading and an asynchronous reset MR input. A LOW on MR resets both the shift register and storage register. Data is shifted on the LOW-to-HIGH transitions of the SHCP input. The data in the shift register is transferred to the storage register on a LOW-to-HIGH transition of the STCP input. If both clocks are connected together, the shift register is always one clock pulse ahead of the storage register. To provide additional hold time in cascaded applications, the serial output QS7 is clocked out on the falling edge of SHCP. Data in the storage register drives the gate of the output extended-drain NMOS (EDNMOS) transistor whenever the output enable input (OE) is LOW. A HIGH on OE causes the outputs to assume a high-impedance OFF-state. Operation of the OE input does not affect the state of the registers. The open-drain outputs are 33 V/100 mA continuous current extended-drain NMOS transistors designed for use in systems that require moderate load power such as LEDs. Integrated voltage clamps in the outputs, provide protection against inductive transients. These voltage clamps make the device suitable for power driver applications such as relays, solenoids and other low-current or medium-voltage loads.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from –40 °C to +85 °C and from –40 °C to +125 °C
- Wide supply range 2.3 V to 5.5 V
- Low R_{DSon}
- Eight Power EDNMOS transistor outputs of 100 mA continuous current
- 250 mA current limit capability
- Output clamping voltage 33 V
- 30 mJ avalanche energy capability
- Enhanced cascading for multiple stages
- All registers cleared with single input
- Low power consumption
- ESD protection:
 - HBM AEC-Q100-002 revision D exceeds 2500 V
 - CDM AEC-Q100-011 revision B exceeds 1000 V

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3. Applications

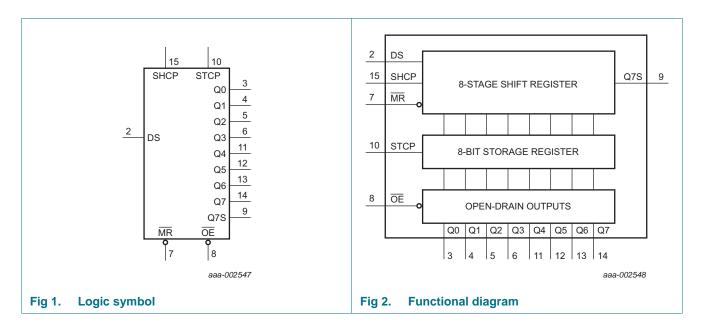
- LED sign
- Graphic status panel
- Fault status indicator

4. Ordering information

Table 1. Ordering information

Type number	Package						
	Temperature range	Name	Description	Version			
NPIC6C596AD-Q100	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1			
NPIC6C596APW-Q100	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1			
NPIC6C596ABQ-Q100	–40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body $2.5 \times 3.5 \times 0.85$ mm	SOT763-1			

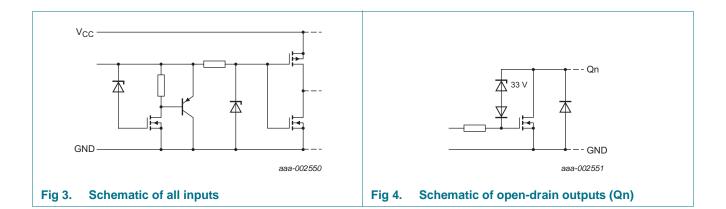
5. Functional diagram

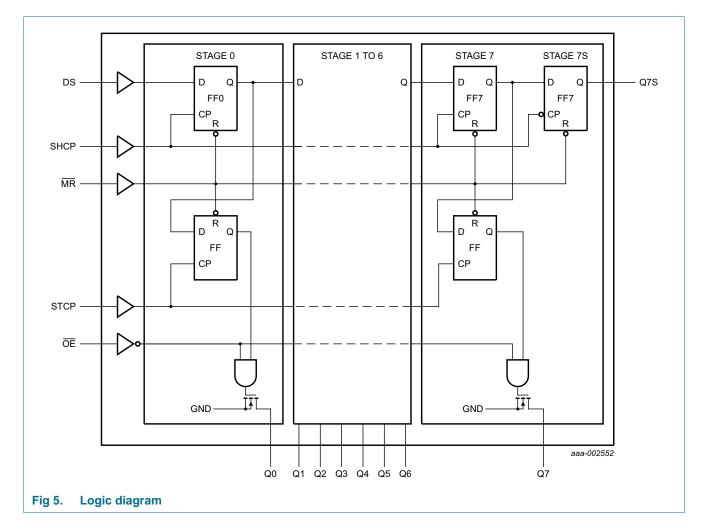


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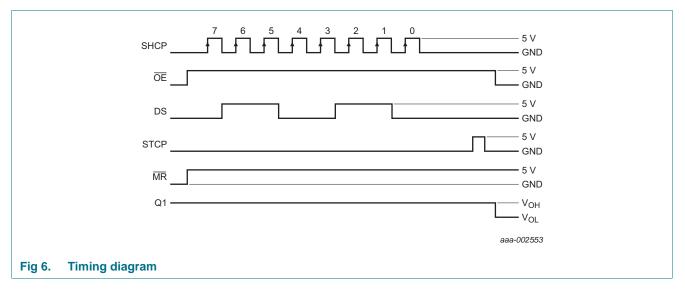
NPIC6C596A-Q100

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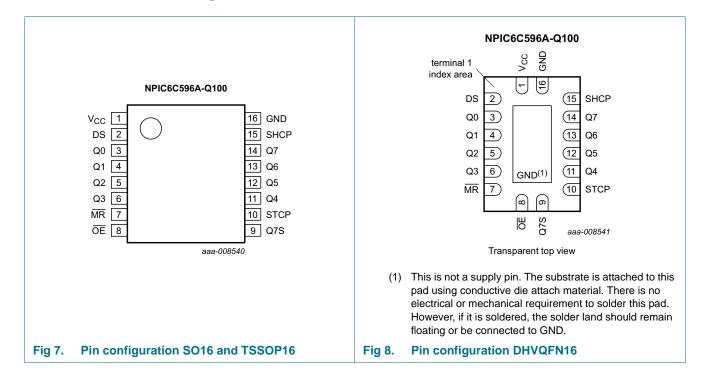




Power logic 8-bit shift register; open-drain outputs



6. Pinning information



6.1 Pinning

Power logic 8-bit shift register; open-drain outputs

6.2 Pin description

Table 2. Pin description		
Symbol	Pin	Description
V _{CC}	1	supply voltage
DS	2	serial data input
Q0, Q1, Q2, Q3, Q4, Q5, Q6, Q7	3, 4, 5, 6, 11, 12, 13, 14	parallel data output (open-drain)
MR	7	master reset (active LOW)
ŌE	8	output enable input (active LOW)
Q7S	9	serial data output
STCP	10	storage register clock input
SHCP	15	shift register clock input
GND	16	ground (0 V)

7. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+7.0	V
VI	input voltage			-0.3	+7.0	V
V _{DS}	drain-source voltage	power EDNMOS drain-source voltage	<u>[1]</u>	-	+33	V
I _{d(SD)}	source-drain diode current	continuous		-	250	mA
		pulsed	[2]	-	500	mA
I _D	drain current	T _{amb} = 25 °C				
		continuous; each output; all outputs on		-	100	mA
		pulsed; each output; all outputs on	[2]	-	250	mA
I _{DM}	peak drain current	single output; T _{amb} = 25 °C	[2]	-	250	mA
E _{AS}	non-repetitive avalanche energy	single pulse; see Figure 9	[3]	-	30	mJ
I _{AL}	avalanche current	see Figure 9	[3]	-	200	mA
T _{stg}	storage temperature			-65	+150	°C

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in accordance		Rating System (IEC 60134). Volt	ages are referenced to	GND (groun	a = 0 v).
Symbol	Parameter	Conditions	Min	Max	Unit
P _{tot}	total power dissipation	T _{amb} = 25 °C	<u>[4]</u>		
	SO16	-	800	mW	
	TSSOP16	-	725	mW	
		DHVQFN16	-	1825	mW
		T _{amb} = 125 °C	<u>[4]</u>		
		SO16	-	160	mW
		TSSOP16	-	145	mW
		DHVQFN16	-	365	mW

Table 3. Limiting values ...continued

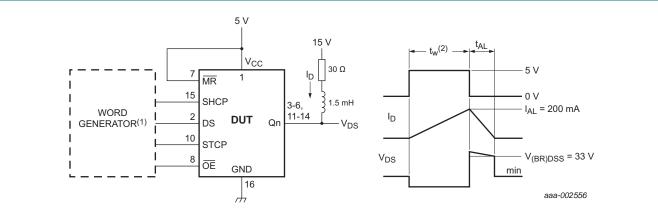
[1] Each power EDNMOS source is internally connected to GND.

[2] Pulse duration \leq 100 μ s and duty cycle \leq 2 %.

[3] $V_{DS} = 15$ V; starting junction temperature (T_i) = 25 °C; L = 1.5 H; avalanche current (I_{AL}) = 200 mA.

[4] For SO16 packages: above 25 °C the value of P_{tot} derates linearly with 6.4 mW/°C.
 For TSSOP16 packages: above 25 °C the value of P_{tot} derates linearly with 5.8 mW/°C.
 For DHVQFN16 packages: above 25 °C the value of P_{tot} derates linearly with 14.6 mW/°C.

7.1 Test circuit and waveform



- (1) The word generator has the following characteristics: $t_r,\,t_f \leq$ 10 ns; Z_O = 50 $\Omega.$
- (2) The input pulse duration (t_W) is increased until peak current I_{AL} = 200 mA. Energy test level is defined as: E_{AS} = $I_{AL} \times V_{(BR)DSS} \times t_{AL}/2$ = 30 mJ.

Fig 9. Test circuit and waveform for measuring single-pulse avalanche energy

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8. Recommended operating conditions

Recommended operating conditions						
Parameter	Conditions		Min	Тур	Max	Unit
supply voltage			2.3	-	5.5	V
input voltage			0	-	5.5	V
drain current	pulsed drain output current; V _{CC} = 5 V; T _{amb} = 25 °C; all outputs on	<u>[1][2]</u>	-	-	250	mA
ambient temperature			-40	-	+125	°C
	Parameter supply voltage input voltage drain current	ParameterConditionssupply voltageinput voltageinput voltagegedrain currentpulsed drain output current; $V_{CC} = 5 V; T_{amb} = 25 \degree C;$ all outputs on	ParameterConditionssupply voltageinput voltageinput voltage $V_{CC} = 5 V; T_{amb} = 25 °C;$ all outputs on	ParameterConditionsMinsupply voltage2.3input voltage0drain currentpulsed drain output current; $V_{CC} = 5 V; T_{amb} = 25 \ ^{\circ}C;$ all outputs on[1][2] -	ParameterConditionsMinTypsupply voltage2.3-input voltage0-drain currentpulsed drain output current; $V_{CC} = 5 V; T_{amb} = 25 \ ^{\circ}C;$ all outputs on-	ParameterConditionsMinTypMaxsupply voltage 2.3 - 5.5 input voltage0- 5.5 drain currentpulsed drain output current; $V_{CC} = 5 V; T_{amb} = 25 ^{\circ}C;$ all outputs on-250

[1] Pulse duration \leq 100 μs and duty cycle \leq 2 %.

[2] Technique should limit $T_j - T_{amb}$ to 10 °C maximum.

9. Static characteristics

Table 5. Static characteristics

At recommended operating conditions unless otherwise specified. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Т	amb = 25 °C	2	Unit
			Min	Typ <mark>[1]</mark>	Max		
V _{IH}	HIGH-level input voltage	$V_{CC} = 3.0 \text{ V} \text{ to } 5.5 \text{ V}$		0.85V _{CC}	-	-	V
V _{IL}	LOW-level input voltage	V_{CC} = 3.0 V to 5.5 V		-	-	0.15V _{CC}	V
V _{OH}	HIGH-level	serial data output Q7S; $V_I = V_{IH}$ or V_{IL}					
	output voltage	$I_{O} = -20 \ \mu A; \ V_{CC} = 3.0 \ V$		2.64	4.49	-	V
		$I_{O} = -4 \text{ mA}; V_{CC} = 3.0 \text{ V}$		2.4	4.2	-	V
V _{OL}		serial data output Q7S; $V_I = V_{IH}$ or V_{IL}					
	voltage	$I_{O} = 20 \ \mu A; \ V_{CC} = 3.0 \ V$		-	0.005	0.12	V
		$I_{O} = 4 \text{ mA}; V_{CC} = 3.0 \text{ V}$		-	0.3	0.6	V
I _I	input leakage current	$V_{CC} = 5.5 \text{ V}; \text{V}_{\text{I}} = \text{V}_{CC}$		-	-	1	μA
V _{(BR)DSS}	drain-source breakdown voltage	I _D = 1 mA		33	37	-	V
V_{SD}	source-drain voltage	diode forward voltage; $I_F = 100 \text{ mA}$		-	0.85	1.2	V
I _{CC}	supply current	logic supply current; $V_{CC} = 5.5 V$; V _I = V _{CC} or GND					
		all outputs off		-	0.004	200	μΑ
		all outputs on	[2]	-	0.006	500	μΑ
		all outputs off; SHCP = 5 MHz; $C_L = 30 \text{ pF}$; see Figure 14 and Figure 16		-	0.75	5	mA
I _{O(nom)}	nominal output current	V_{DS} = 0.5 V; T_{amb} = 85 °C; I_{out} = I_D	<u>[3][4][5]</u>	-	140	-	mA
I _{DSX} drain cut-off current	drain cut-off	$V_{CC} = 5.5 \text{ V}; V_{DS} = 30 \text{ V}$		-	0.002	0.2	μA
	current	V_{CC} = 5.5 V; V_{DS} = 30 V; T_{amb} = 125 °C		-	0.15	0.3	μA
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At recomi	At recommended operating conditions unless otherwise specified. Voltages are referenced to GND (ground = 0 V).					
Symbol	Parameter	Conditions	Г	amb = 25 °C		Unit
			Min	Typ <mark>[1]</mark>	Max	
R _{DSon} drain-source on-state resistance	see Figure 17 and Figure 18 [3][4]					
	$V_{CC} = 3.0 \text{ V}; \text{ I}_{D} = 50 \text{ mA}$	-	3.0	11	Ω	
		V_{CC} = 3.0 V; I_{D} = 50 mA; T_{amb} = 125 $^{\circ}C$		5.4	14	Ω
		$V_{CC} = 3.0 \text{ V}; I_D = 100 \text{ mA}$	-	3.1	12	Ω

Table 5. Static characteristics ...continued

At recommended operating conditions unless otherwise specified. Voltages are referenced to GND (ground = 0 V).

[1] Typical values are measured at T_{amb} = 25 $^{\circ}C$ and V_{CC} = 5.0 V.

[2] Output currents below 250 mA current limit.

[3] Technique should limit $T_i - T_{amb}$ to 10 °C maximum.

[4] These parameters are measured with voltage-sensing contacts separate from the current-carrying contacts.

[5] Nominal output current is defined for a consistent comparison between devices from different sources. It is the current that produces a voltage drop of 0.5 V at T_{amb} = 85 °C.

10. Dynamic characteristics

Table 6.Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); For test circuit, see Figure 14.

Symbol	Parameter	Conditions		T _{amb} = 25 °C			Unit
				Min	Typ <mark>[1]</mark>	Max	
t _{PLH}	LOW to HIGH propagation delay	\overline{OE} to Qn; I _D = 75 mA; see <u>Figure 10</u> and <u>Figure 19</u>	ľ	-	97	-	ns
t _{PHL}	HIGH to LOW propagation delay	\overline{OE} to Qn; I _D = 75 mA; see <u>Figure 10</u> and <u>Figure 19</u>		-	9	-	ns
t _r	rise time	\overline{OE} to Qn; I _D = 75 mA; see <u>Figure 10</u> and Figure 19		-	60	-	ns
t _f	fall time	\overline{OE} to Qn; I _D = 75 mA; see <u>Figure 10</u> and <u>Figure 19</u>		-	18	-	ns
t _{pd}	propagation delay	SHCP to Q7S; $I_D = 75$ mA; see Figure 11	[2]	-	5	-	ns
f _{max}	maximum frequency	SHCP; I _D = 75 mA; see Figure 11	[3]	-	-	10	MHz
t _{rr}	reverse recovery time	I _F = 100 mA; dI/dt = 10 A/μs; see <u>Figure 13</u>	<u>[4][5]</u>	-	120	-	ns
t _a	reverse recovery current rise time	I _F = 100 mA; dI/dt = 10 A/μs; see <u>Figure 13</u>	<u>[4][5]</u>	-	100	-	ns
t _{su}	set-up time	DS to SHCP; see Figure 12		15	-	-	ns
t _h	hold time	DS to SHCP; see Figure 12		15	-	-	ns
t _W	pulse width			40	-	-	ns

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 5.0 V.

[2] t_{pd} is the same as t_{PLH} and t_{PHL}.

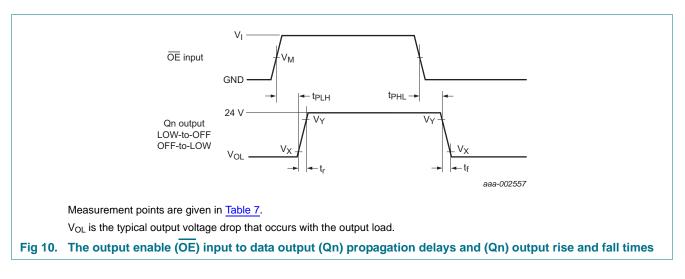
[3] This is the maximum serial clock frequency assuming cascaded operation where serial data is passed from one stage to a second stage. The clock period allows for SHCP → Q7S propagation delay and setup time plus some timing margin.

[4] Technique should limit $T_j - T_{amb}$ to 10 °C maximum.

[5] These parameters are measured with voltage-sensing contacts separate from the current-carrying contacts.

Power logic 8-bit shift register; open-drain outputs





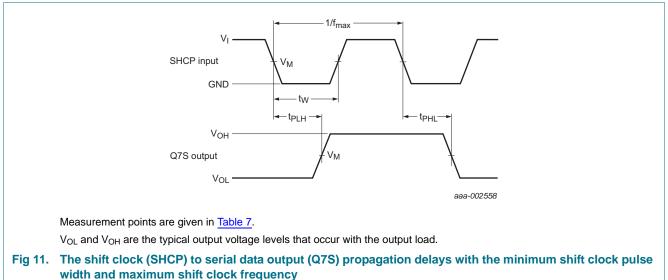


Table 7. Measurement points

Supply voltage	Input	Output		
V _{CC}	V _M	V _M	V _X	V _Y
5 V	0.5V _{CC}	0.5V _{DS}	0.1V _{DS}	0.9V _{DS}

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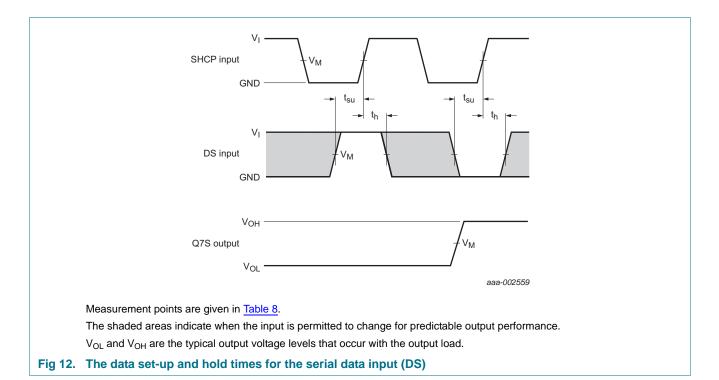
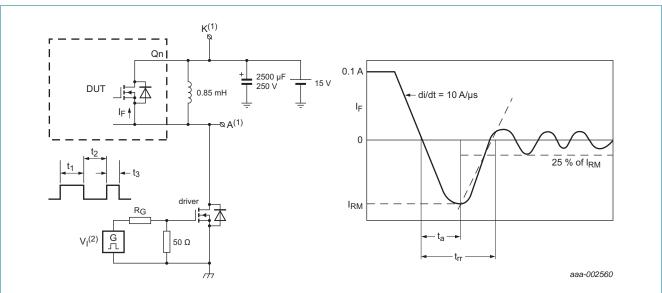


Table 8.Measurement points

Supply voltage	Input	Output
V _{cc}	V _M	V _M
5 V	0.5V _{CC}	0.5V _{CC}



- (1) The open-drain Qn terminal under test is connected to testpoint K. All other terminals are connected together and connected to testpoint A.
- (2) The V₁ amplitude and R_G are adjusted for dl/dt = 10 A/ μ s. A V₁ double-pulse train is used to set I_F = 0.1 A, where t₁ = 10 μ s, t₂ = 7 μ s and t₃ = 3 μ s.

Fig 13. Test circuit and waveform for measuring reverse recovery current

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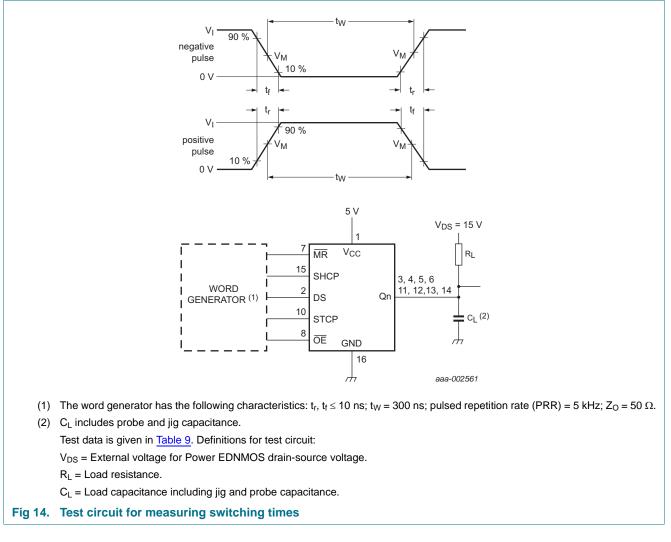


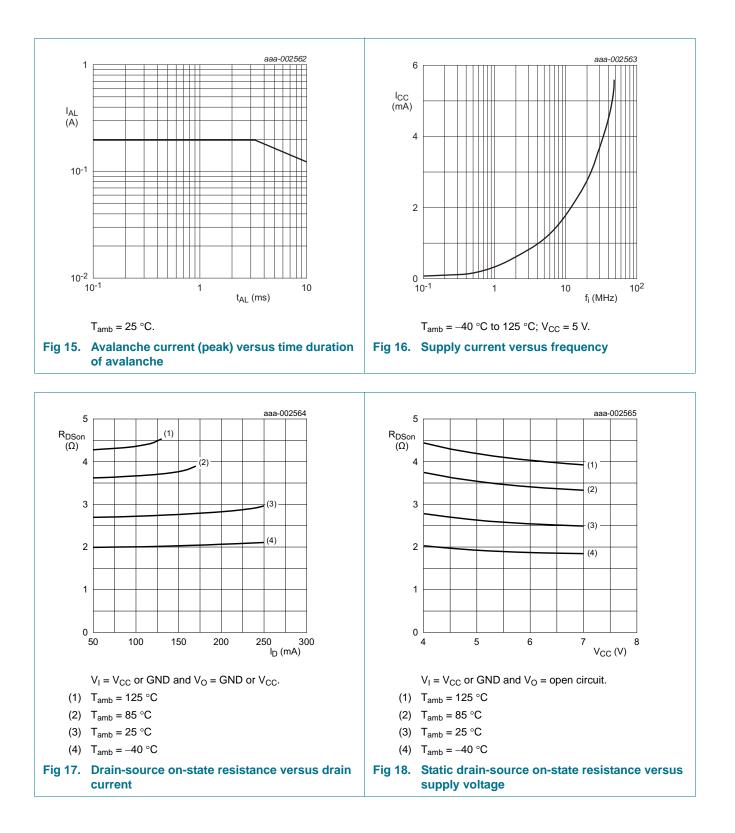
Table 9. Test data

Supply voltage	Input			Load		
	VI	t _r , t _f	V _M	CL	R _L	
5 V	5 V	≤ 10 ns	50%	30 pF	200 Ω	

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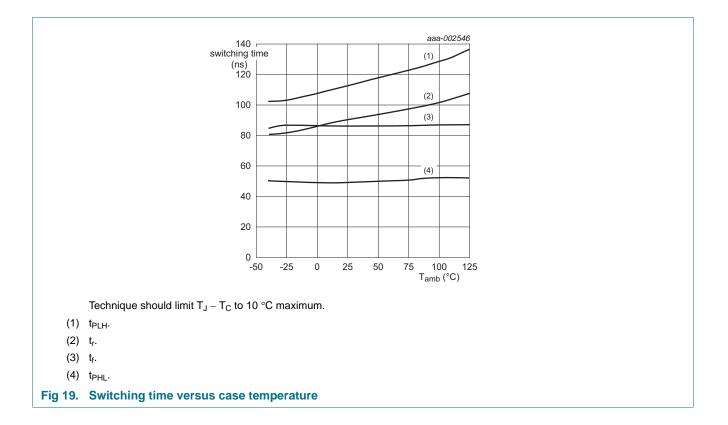
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11. Package outline

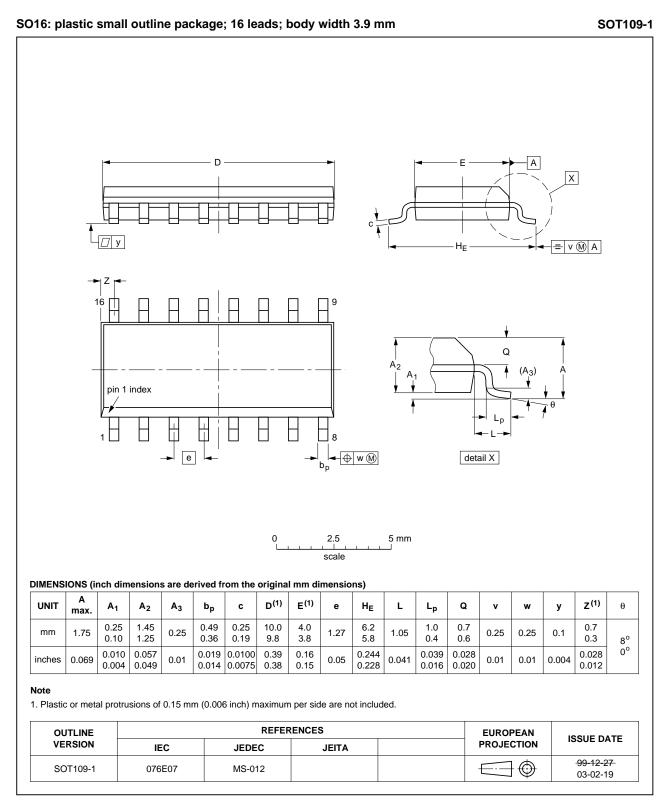


Fig 20. Package outline SOT109-1 (SO16)

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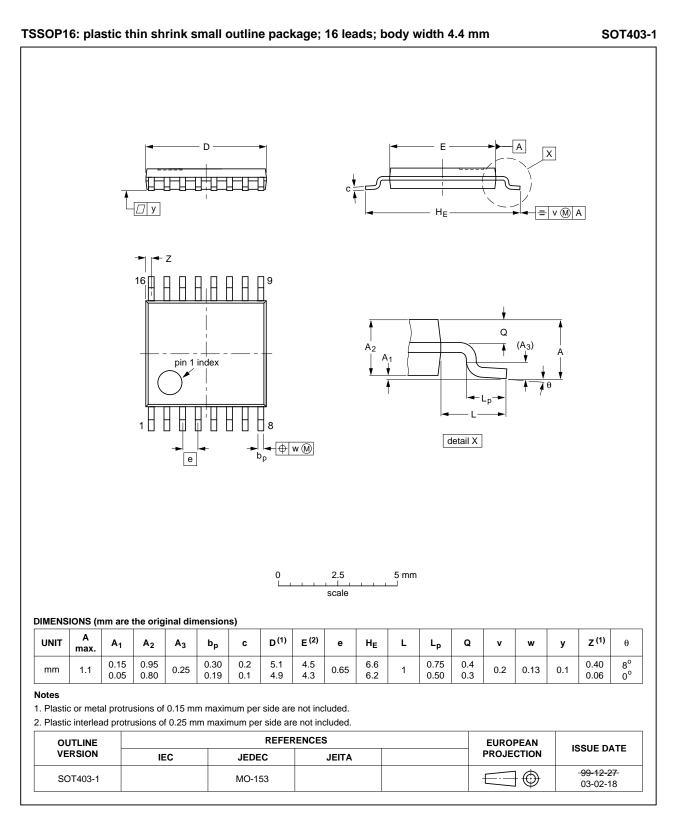
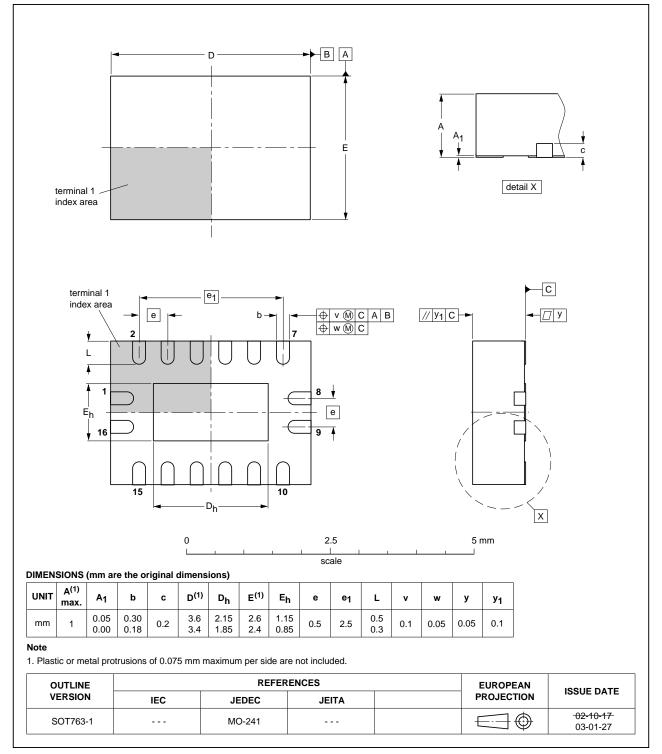


Fig 21. Package outline SOT403-1 (TSSOP16)

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DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

Fig 22. Package outline SOT763-1 (DHVQFN16)

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12. Abbreviations

AcronymDescriptionCDMCharged Device ModelCMOSComplementary Metal Oxide SemiconductorDUTDevice Under TestEDNMOSExtended Drain Negative Metal Oxide SemiconductorESDElectroStatic DischargeHBMHuman Body ModelTTLTransistor-Transistor Logic	Table 10.	Abbreviations
CMOSComplementary Metal Oxide SemiconductorDUTDevice Under TestEDNMOSExtended Drain Negative Metal Oxide SemiconductorESDElectroStatic DischargeHBMHuman Body Model	Acronym	Description
DUTDevice Under TestEDNMOSExtended Drain Negative Metal Oxide SemiconductorESDElectroStatic DischargeHBMHuman Body Model	CDM	Charged Device Model
EDNMOSExtended Drain Negative Metal Oxide SemiconductorESDElectroStatic DischargeHBMHuman Body Model	CMOS	Complementary Metal Oxide Semiconductor
ESD ElectroStatic Discharge HBM Human Body Model	DUT	Device Under Test
HBM Human Body Model	EDNMOS	Extended Drain Negative Metal Oxide Semiconductor
· · · · · · · · · · · · · · · · · · ·	ESD	ElectroStatic Discharge
TTL Transistor-Transistor Logic	HBM	Human Body Model
·	TTL	Transistor-Transistor Logic

13. Revision history

Table 11. Revision history					
Document ID	Release date	Data sheet status	Change notice	Supersedes	
NPIC6C596A_Q100 v.1	20131018	Product data sheet	-	-	

Power logic 8-bit shift register; open-drain outputs

14. Legal information

14.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Power logic 8-bit shift register; open-drain outputs

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